MULTI-BIT-PER-CELL FLASH EEPROM MEMORY WITH REFRESH Inventors: Hock C. So and Sau C. Wong Atty. Docket No. M-10277-3C US Sheet 1 of 4

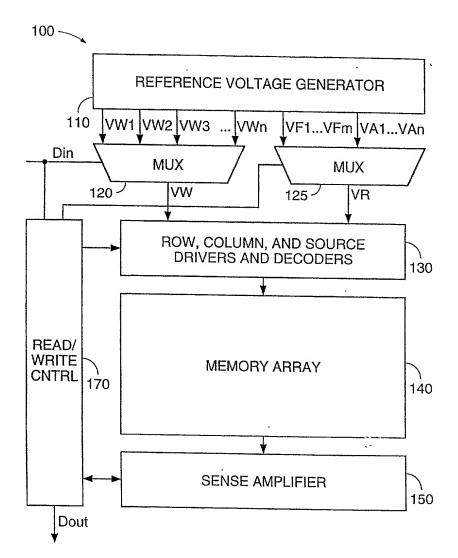


FIG. 1

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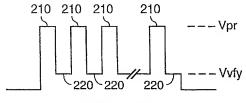


FIG. 2A

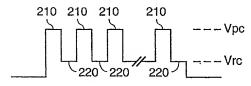


FIG. 2B

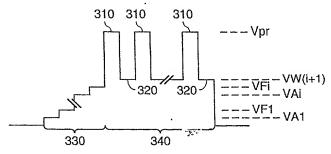


FIG. 3A

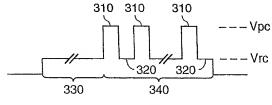
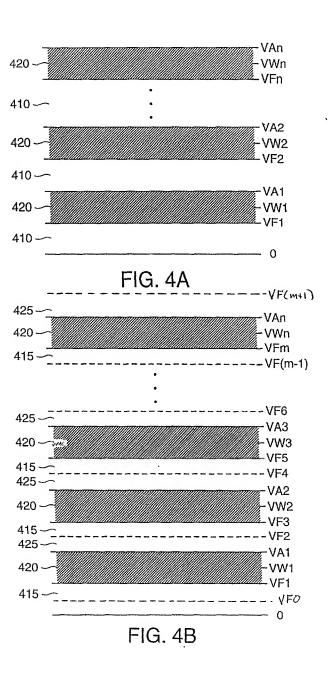


FIG. 3B

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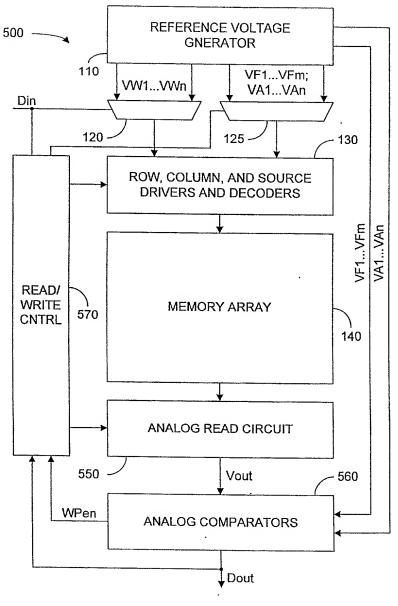


FIG. 5